## SKT 240

WKRUNSKT 240/08E

 $V_{\rm RSM}$ 

V

500

900 1300

1500

1700

1900

 $V_{\rm RRM}, V_{\rm DRM}$ 

V

400 800

1200

1400

1600

1800

SKT 240/04E

SKT 240/08E

SKT 240/12E

SKT 240/14E

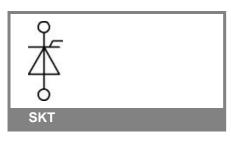
SKT 240/16E

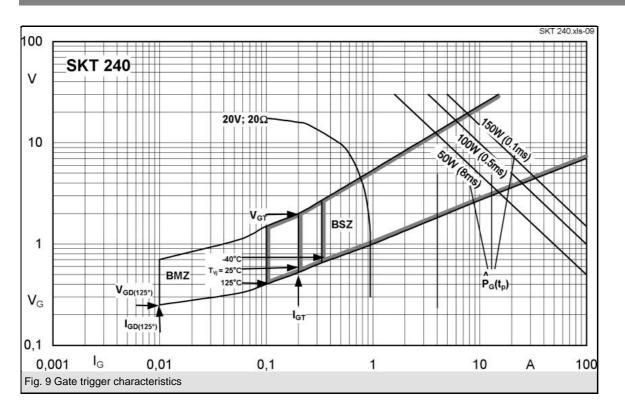
SKT 240/18E

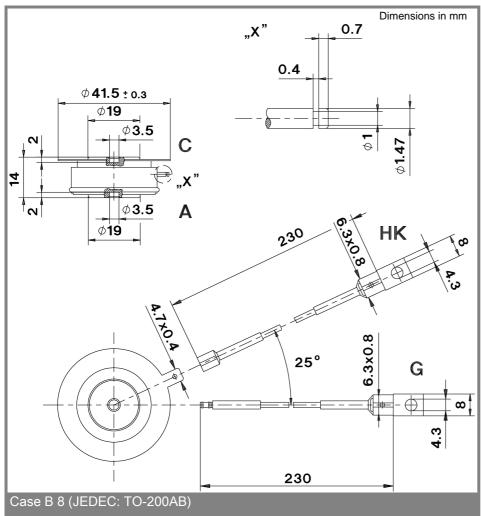
	Symbol	Conditions	Values	Units
Capsule Thyristor	I <sub>TAV</sub>	sin. 180; T <sub>c</sub> = 100 (85) °C;	204 (282 )	А
	I <sub>D</sub>	2 x P8/180; T <sub>a</sub> = 45 °C; B2 / B6	275 / 390	А
1 · · · · · · · · · · · ·		2 x P8/180F; T <sub>a</sub> = 35 °C; B2 / B6	540 /750	A
Line Thyristor	I <sub>RMS</sub>	2 x P8/180; T <sub>a</sub> = 45 °C; W1C	300	А
	I <sub>TSM</sub>	T <sub>vi</sub> = 25 °C; 10 ms	5000	А
		T <sub>vj</sub> = 125 °C; 10 ms	4500	А
SKT 240	i²t	T <sub>vj</sub> = 25 °C; 8,3 10 ms	125000	A²s
		T <sub>vj</sub> = 125 °C; 8,3 10 ms	101000	A²s
	V <sub>T</sub>	T <sub>vi</sub> = 25 °C; I <sub>T</sub> = 1000 A	max. 2,3	V
	V <sub>T(TO)</sub>	T <sub>vj</sub> = 125 °C	max. 1	V
	r <sub>T</sub>	T <sub>vj</sub> = 125 °C	max. 1,4	mΩ
	I <sub>DD</sub> ; I <sub>RD</sub>	$T_{vj}$ = 125 °C; $V_{RD}$ = $V_{RRM}$ ; $V_{DD}$ = $V_{DRM}$	max. 40	mA
<b>F</b> and the set	t <sub>gd</sub>	T <sub>vj</sub> = 25 °C; I <sub>G</sub> = 1 A; di <sub>G</sub> /dt = 1 A/μs	1	μs
Features	t <sub>gr</sub>	V <sub>D</sub> = 0,67 * V <sub>DRM</sub>	2	μs
Hermetic metal case with ceramic	(di/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C	max. 125	A/µs
insulator	(dv/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C	max. 1000	V/µs
Capsule package for double	t <sub>a</sub>	T <sub>vi</sub> = 125 °C ,	50 150	μs
sided cooling	t <sub>q</sub> I <sub>H</sub>	T <sub>vj</sub> = 25 °C; typ. / max.	150 / 400	mA
Shallow design with single sided	Ι <sub>L</sub>	T <sub>vj</sub> = 25 °C; typ. / max.	300 / 1000	mA
cooling	V <sub>GT</sub>	T <sub>vi</sub> = 25 °C; d.c.	min. 2	V
<ul> <li>International standard case</li> </ul>	I <sub>GT</sub>	$T_{vj} = 25 \text{ °C}; \text{ d.c.}$	min. 150	mA
Off-state and reverse voltages up	$V_{GD}$	$T_{vj} = 125 \text{ °C; d.c.}$	max. 0,25	V
to1800 V	I <sub>GD</sub>	T <sub>vj</sub> = 125 °C; d.c.	max. 10	mA
Typical Applications	R <sub>th(j-c)</sub>	cont.; DSC	0,07	K/W
Typical Applications	R <sub>th(j-c)</sub>	sin. 180; DSC / SSC	0,072 / 0,151	K/W
DC motor control	R <sub>th(j-c)</sub>	rec. 120; DSC / SSC	0,08 / 0,168	K/W
(e. g. for machine tools)	R <sub>th(c-s)</sub>	DSC / SSC	0,02 / 0,04	K/W
<ul> <li>Controlled rectifiers</li> </ul>	Τ <sub>νj</sub>		- 40 + 125	°C
(e. g. for battery charging)	T <sub>stg</sub>		- 40 + 130	°C
AC controllers	V <sub>isol</sub>		-	V~
(e.g. for temperature control)	F	mounting force	4 5	kN
Recommended snubber network	а			m/s²
e. g. for $V_{VRMS} \le 400 V$ :	m	approx.	55	g
R = 33 Ω/32 Ŵ, C = 0,47 μF	Case		B 8	

 $I_{\text{TRMS}}$  = 600 A (maximum value for continuous operation)

 $I_{TAV}$  = 240 A (sin. 180; DSC;  $T_c$  = 93 °C)







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